Fabrication of an Implantable Micro-pressure Sensor to Measure Deviation Within the Cochlea

Fabricación de un Micro Sensor de Presión Implantable Aplicado a Medir Desviaciones Dentro de la Cochlea

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Abstract

The Cochlear Implant is broadly worn by people with deep hearing damage. This device makes up an electrode array to electrically stimulate the auditory nerves. When the electrode is implanted into the inner ear by surgery, the scala tympani is ill-treated due to the strong pressure applied on the internal ear structures. To minimize this intra-cochlear trauma, it is proposed to fabricate a micro pressure-sensor and built it in the electrode array, in such a way that the pressure applied by the electrode is measured. This work selected the MEMS SU-8 Fabry-Perot interferometer-based pressure sensor. This paper describes the sensor fabrication process carried out, and explains how to integrate this sensor with the electrode array.

Index Terms: Cochlear implant, MEMS sensor, SU8 material, Intra-cochlear trauma

Resumen

El implante coclear es ampliamente utilizado por personas con año auditivo profundo. Este dispositivo se compone de un conjunto de electrodos que estimulan eléctricamente los nervios auditivos. Cuando el electrodo es insertado quirúrgicamente en el oído interno, la escala timpani es maltratada debido a las considerables presiones aplicadas a las estructuras internas del oído. Esto ocasiona trauma, lo cual es indeseado, y es principalmente causado por el contacto del electrodo con las paredes de la cóclea. Para minimizar este trauma, se propone fabricar un MEMS sensor de presión para que sea integrado al conjunto de electrodos; permitiendo medir la presión aplicada al oído. Este trabajo ha seleccionado el SU8 MEMS sensor de presión basado en el efecto de interferencia óptica. Este artículo describe el proceso de fabricación del sensor y como se puede integrar al array de electrodos.

Palabras clave: implante coclear, material SU8, sensores MEMS, trauma Intra - coclear
I. INTRODUCTION

The cochlear implant uses an array of electrodes to electrically stimulate the auditory nerves. Specifically, this electrode is inserted into the inner ear, nearest the modiolus. During the surgery, doctors must not damage the delicates intracochlear structures [1], [2]. However, electrode displacement along the scale tympani causes severe pressure on the inner ear walls. At present, The Cochlear Corporation commercializes two cochlear implants devices: The Nucleus 24 Contour Advanced and The Hybrid Cochlear Implant. In particular, The Hybrid implant stimulates the auditory nerves both acoustically (at low frequencies) and electrically (at high frequencies), and therefore it requires to remain the ear structures.

Both, The Nucleous 24 Contour Advanced and The Hybrid Cochlear Implant, are inserted following a technique called "Advanced Off Stylet (AOS)". The aim of AOS is simply to reduce intra-cochlear damage caused by pressure applied on cochlea walls. At present, The AOS technique has shown good results in terms of minimizing pressure prompt that a strict surgery procedure is followed.

The SU8 Fabry-Perot Interferometer-based MEMS pressure sensor is selected to be integrated with the electrode array, intended to measure the pressure during the insertion. The literature indicates that this micro-sensor is already fabricated [3],[4]. However, this sensor is made only to measure orthogonal pressure. In this application, it is preferably the sensor readout pressure from different directions (not only orthogonal). For that, it is proposed to deposit a rubber-elastic material (polydimethyl-siloxane - PDMS) on top of the sensor membrane.

In this paper, the section II explores the AOS technique to find potential causes of trauma during electrode insertion. The section III specifies aspects of sensor design, such as type of material and MEMS structure. The section IV introduces the SU8 Fabry-Perot interferometer-based sensor with mathematical formulations. This section also indicates the dimensions of MEMS cavity. The section V describes the main properties of sensor materials as well as fabrication process. At the end, the MEMS device was fabricated without depositing the PDMS material.

II. POTENTIAL INTRA-COCHLEAR TRAUMA

The Cochlear Nucleus 24 Contour Advance is one of the most novel cochlear implant launched on the market. Unlike its previous models, The Nucleus 24 brings new insertion technique "Advanced Off Stylet (AOS)", and the electrode array comes up pre-curved with a soft-tip. Theoretically, the electrode allows minimizing intracochlear damage while it is hosted nearest the modiolus [5]. The process of insertion begins setting the electrode over the stylet. Then, doctors put the tip of the styled mounted electrode at the beginning of cochlea first turn (see figure 1-A). A white line marked on the shank silicon enables to guide the initial position of the electrode.

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However, the AOS is not easy to follow. According to this technique, the styled mounted electrode must be putted, initially, on the position indicated in figure 1-A. Although the white mark on the shank provides visual help to doctors for initial placement, this is not reliable due to the distance from cochleostomy (opening to access the scala tympani) to the first turn varies [8]. Incorrect initial position is often and doctors introduce the electrode array further than estimated initial position, causing trauma (see wrong contact pressure figure 1-A).

On the other hand, the figure 1-C shows the electrode tip touching the cochlea innerwall. In particular, the auditory nerves are connected with the organ de corti and this is located along the innerwall. Although it is not reported, strong contact pressure on the inner walls might happen with AOS and it would damage the nerve fibers. Hypothetically, this damage might cause variation of conductivity between the electrode and stimulated nerve.

The AOS technique has another disadvantage. While introducing the electrode, the inner wall experiences friction. The array has a side where the electrodes and the silicon are not equally leveled (see figure 2) and this might lead to severe friction on wall surfaces.

Around the cochlea apex, the remaining hair cells are acoustically stimulated by The Hybrid Cochlear Implant. During electrode insertion, it is a concern to preserve the whole hair cells. In the cochlea, the cells stay on the basiliar membrane, specifically on the scala media. It is feasible that during insertion, the electrode shakes strongly the perilymph (fluid in the cochlea) and this might causes strong deviation of the basiliar membrane. It has been demonstrated that considerable basilar membrane displacement leads to destroy hair cells.

### III. SENSOR APPROACH

#### A. Applicability

This document proposes an approach to minimize risk of intracochlear damage. A micro-pressure sensor joined at the electrode tip would measure and monitor pressure during electrode insertion. Likely, the monitoring pressure would plot peaks of pressure, meaning strong contact on the cochlea walls.

#### B. Design Aspects

Requirements: After full insertion, the sensor must be removed from the implant. The sensor must be highly sensitive.

The SU8 Fabry-Perot Interferometer based pressure sensor is fabricated by defining a MEMS cavity which connects with an optical fiber (see figure 3-B). For better explaining, this paper calls the cavity as “head” and the optical fiber as “tail”.

Following, this paper proposes a manner of building the sensor in the implant. The silicone electrode should have a hole all along the shank. Plus, the sensor head should be joined with the electrode tip (see figure 3-AB). The tail is only withdrawn from the electrode after full insertion. The optical fiber is removed by pulling down from one electrode end. In this way, the cavity breaks up and the sensor tail can be easily removed (see figure 3-C).
IV. THE Su8 Fabry-Perot Interferometer Based MEMS Pressure Sensor

A Fabry-Perot interferometer-based MEMS sensor is made up a source of light, guided by an optical fiber, and beamed towards a MEMS membrane (see figure 4). In particular, this membrane is made of a reflective material. When the light is transmitted, most of it is sent back via the optical fiber. The power of reflective light is modulated by membrane deflection (the amount of reflected light depends on the gap distance between the optical fiber end and the membrane, figure 4-B). A light meter is connected with one end of the optical fiber in order to measure the light back power. The relationship between light back power and membrane deflection establishes the pressure applied on the sensor.

To fabricate the micro-sensor, it is selected the polymer SU8 (see section 4 for more details). The MEMS sensor cavity is defined as shown in figure 6. In particular, the SU8 is a photo-resistor used to shape MEMS layers and it is transparent. The Fabry-Perot interferometer-based sensor requires a reflective layer, therefore, it is deposited a thin layer of Aluminum on membrane backside (see figure 4-C).

This paper proposes to apply a rubber-elastic material polydimethylsiloxane (PDMS) on top of the membrane (see figure 4-C) to measure pressures in all directions. In this paper, the PDMS layer is only proposed and not applied to the fabricated sensor.

![Fig. 3] Withdrawing the optical fiber from the electrode. (A-B) The sensor head sensor is fixed at the electrode tip. (C) The sensor tail is taken off by pulling down.

![Fig. 4] SU8 Fabry-Perot interferometer-based MEMS pressure sensor. (A) The sensor with the light emitter and power meter. (B) The SU8 Fabry-Perot sensor is coupled with the optical fiber. (C) The sensor with applied rubber-elastic material.
### TABLE I

<table>
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<th>Physical Parameters</th>
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<tr>
<td>Refraction index $n_1$</td>
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<tr>
<td>Refraction index $n_2$</td>
<td>1.4</td>
</tr>
<tr>
<td>Light wavelength (nm) $\lambda$</td>
<td>1310</td>
</tr>
<tr>
<td>Reflective backside material $r$</td>
<td>0.92</td>
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</table>

### A. Gap Distance

Reflected power light depends on the gap distance between the membrane and the optical fiber end. Mathematically, the effect of power light variations due to a reflective plane was studied by Yeh [8]. In the formula 1, Yeh assumed coherent light emitted orthogonally to membrane deviation is upper than $\lambda/4$ wards a plane in motion. The SU8 MEMS pressure sensor is based on Yeh's formula.

When pressure is applied on the membrane, the gap distance changes. This behavior is similar to Yeh's formulation.

\[
R = \frac{r_{01} + r_{12}e^{2\Omega}}{1 + r_{01}r_{12}e^{2\Omega}} \tag{1}
\]

Formula 1 refers to light-power reflection. $r_{01}$ and $r_{12}$ are calculated by the refraction index of both the gap distance (named $n_2$) and the optical fiber (named $n_1$), respectively. In addition, $r$ is the reflectivity of the backside (thin layer of aluminum) and $d$ is the gap distance (see formulas 2, 3 and 4).

\[
r_{01} = \frac{n_1 - n_2}{n_1 + n_2} \tag{2}
\]

\[
r_{12} = -\sqrt{r} \tag{3}
\]

\[
\Omega = \frac{2\pi n_2 d}{\lambda} \tag{4}
\]

The sensor is designed at high sensitivity. The gap distance between optical fiber end and membrane needs to be calculated. For that, the formula 1 was 4.

The gap distance is selected in the middle of the wavelength maximum and minimum values.

Finally, MEMS cavity is fabricated with a gap distance of (0.529 $\mu$m). It is important to guarantee this separation in order to have a sensor with predefined mathematical formulations.

### B. Membrane Thickness

Membrane thickness is dimensioned such that the maximum deviation is $\lambda/4$ [3]. The membrane is deflected till its elasticity bounding. The formula 5 calculates this deviation:

\[
W_{max} = \frac{3P_{max}R(1 - v^2)}{16E.t^3} \tag{5}
\]

$P_{max}$ is the maximum applied pressure, $R$ is half of membrane diameter, $v$ is the Poisson's ratio of SU8 material, $E$ is the Youngs modulus, $t$ is the thickness and $W_{max}$ is the maximum deviation.

A long iterative procedure was carried out to calculate the membrane thickness, using the formula 5. However, a method explained in [3].

The sensor is designed at high sensitivity. The gap distance between optical fiber end and membrane needs to be calculated. For that, the
formula 1 was plotted, taking the values indicated in table 1.

From figure 5, it is shown that reflected light has a periodic waveform. This behavior leads to ambiguous measurements in case of allows quickly to find the value. Due to this procedure is nonlinear, its recommended to cut the membrane deviation at $3\lambda/20$.

Due to membrane displacement is small, non-linearity does not care while calculating thickness. By using the formula 5, taking the values indicated in table 2. the membrane thickness for the sensor is 0.71 µm.

| TABLE II  
<table>
<thead>
<tr>
<th>MATERIALS PARAMETERS</th>
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<tr>
<td>Poisson’s ratio</td>
</tr>
<tr>
<td>Maximum pressure (units: Pa)</td>
</tr>
<tr>
<td>Membrane diameter (µm)</td>
</tr>
<tr>
<td>Young’s modulus (GPa)</td>
</tr>
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</table>

The thickness was found in this way:

- First, calculate membrane deviation by using the formula 5 and taking the values of table 2. A software tool is recommended to use.

- Iteratively, find the thickness till deviation of $\lambda/4$ is raised. During calculation, you can modify the thickness in steps of $\lambda/2n3$.

V. MATERIALS AND FABRICATION

A. The polymer SU8

The SU8 is a negative photo-resistor based on epoxy components, widely used to create thin layer of 0.6 µm to 300µm. Also, it is used to fabricate multilayer coating thickness up to 2-3 mm [10], [11]. Chemically, it is composed by triarylimium sulphonium salts and a photoacid [12], [13]. When the SU8 is irradiated with UV light, a high concentration of strong acid is formed which acts as a catalyst for the crosslinking process. When the polymer is heating, it actives the crosslinking and the sensitivity is increased. In particular, the photoacid is sensitive to UV irradiation in the range of 350-400 nm. A normal SU8 process is described in [15].

Mechanical and chemical stability of SU8 leads to use this material to fabricate MEMS structures. Normally, the SU8 has a Youngs modulus of 2-5 GPa [17]. In addition, the cost of SU8 fabrication is less than silicon wafer and this makes attractive for the industry [14]. Good chemical compatibility and biostability has been also reported [16]. Unfortunately, the SU8 presents adhesion selectivity with some materials.

B. The elastic Polydimethylsiloxane (PDMS)

The polydimethylsiloxane (PDMS) is a silicon-rubber based on organic polymer. This is physically stable and used in MEMS as spring material, micromechanical sensors (accelerometers tactile sensors), in packing to isolate Bio micro-fluid system from external environment [19], in valves, pumps, circuits and optical systems (adaptive lenses) [20].

PDMS properties remain stable at temperature range of -50 to 200 C [21]. Chemical and physical characteristics of PDMS are flexible (shear modulus varies between 100kPa and 3MPa), it is optically transparent to wavelength near 256 nm, high dielectric strength (14 V µm-1), small refraction index 1.4, high permeability and compressibility with nontoxic nature [22]. Unfortunately, low surface energy does not lead to good adhesion with metals and special techniques need to be used for bonding [23]. Fabrication of PDMS layer is realized by spinning, with thickness depending on speed and time. Typical spin speed vs. thickness curve shows a hyperbolic behavior. During coating process, the rotational movements of the rubberelastic material causes shear variations between particles, and PDMS viscosity could be altered [24].

The PDMS has been also reported as biocompatible [25]. Low price and bioproperties are interesting for applications on biomedical devices.
such as catheters, drainage tubing, insulation or peacemakers and ear and nose implants [26].

**C. MEMS Cavity (sensor head)**

The sensor cavity is fabricated by creating 4 layers deposited on a crystal wafer. The first three layers have the same diameter (135 µm) but different thickness. The layer 1 is the membrane and has a thickness of 0.71 µm. The layer 2 is made of aluminum and it is developed on top of the layer 1, with a thickness of 0.4 µm. The layer 3 defines the gap distance between the optical fiber and the membrane backside. It has a thickness of 0.57 µm. The last layer is made for fitting the optical fiber with the cavity. It has a thickness of 10 µm.

The SU8 material was acquired by The Micho-Chem Company [27]. The cavity fabrication process was performed in a clean room. The structure of the sensor cavity and thicknesses are shown in figure 6.

![Fig. 6 The MEMS sensor cavity was fabricated by planar process (layer by layer).](image)

1) **Fabrication process**

Each layer of the sensor cavity was fabricated as follows:

Initially, a sacrificial layer (Omnicoat) was deposited on a wafer, spinning at 2000 rpm for 20 seconds. Then, it was dried on a hotplate by 65 C for 1 minute.

**Layer 1:** The SU8-2000.5 material was deposited on the sacrificial layer at 3 ml on the wafer and spinning at 1100 rpm by 20 seconds. Thickness of 0.73 µm was obtained.

**Layer 2:** The material was Aluminum. A plasma sputter was used for this deposition. The wafer was entered in the sputter by 2.12 minutes at 300 watts. A layer thickness of 0.4 µm was obtained. The circular shape of the reflective layer was developed by lithography.

**Layers 3 – 4:** The layers 3 and 4 were deposited by coating the wafer again with SU8-2000.5 and SU8-2010, respectively. The fabrication process was the same as made for the first layer, unlike the spin speed was 2000 rpm (for the layer 3) and 600 rpm (for the layer 4).

4). The thicknesses were 0.61 µm and 11 µm, respectively.

**D. Optical Fiber and Cavity**

One optical fiber end is inserted in the cavity and then glued. Ideally, the optical fiber should fits exactly with the cavity hole but it is not possible at all.

A special machine was adapted to insert the optical fiber end with the cavity. By experiments, it was found that the glue must be highly viscous. Additionally, it is preferably that the optical fiber end fits almost exactly with the cavity. If the fiber remains loose after it is in, the glue can enter in the cavity and the gap distance between the membrane and optical fiber end will be glued, which is completely undesired.

**E. Test and Results**

The sensor was finally fabricated without depositing the PDMS material. The noglued optical fiber end was connected with a source of light and a derivation was connected with a light power meter. Several measurements were performed. The range of pressure applied was 0- 3.5 KPa. The entire measurements were recorded and plotted using Matlab. The figure 7 shows the plotted results.
The graph "reflected-light-power" vs "pressure". The measurements were performed by putting the sensor in a chamber, and varying the pressure from 0 - 3.5 KPa. The sensor sensitivity was $-4 \times 10^{-5}$ µW/Pa.

VI. CONCLUSIONS

The next step will be to perform tests, using the electrode array with the sensor. Likely, some aspects should take into account. The cochlea is filled by a liquid and during the insertion turbulence can happens, leading to noisy measurements. This noise would not allow monitoring, properly, pressure by contact.

During fabrication process, it was found that MEMS technology still requires to overcome some limitations. MEMS assembly is not easy and for the SU8 MEMS sensor, it was very hard to join the cavity with the optical fiber. In the near future, it will require new assembly machines for this new technology.

Intra-cochlear trauma is a concern and there is not a clear way of minimize it yet. Integrating a MEMS pressure sensor into the electrode array could, in certain way, to monitor pressure during insertion but it does not guarantee that trauma will be minimized. New surgical technique should be evaluated.

REFERENCES